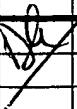





Substitute for form 1449A/PTOL-101 INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>		Complete If Known	
		Application Number	10/816,259
		Filing Date	March 31, 2004
		First Named Inventor	Mukul P. Renavikar
		Art Unit	2818
		Examiner Name	Le, Dung Anh
		Attorney Docket Number	42P19022
Sheet	1	of	2

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No.¹	Document Number	Publication Date Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code* (if known)			
		US-2003/0179617	09-25-2003	Gudesen et al.	
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		Country Code* - Number* - Kind Code* (if known)				
		WO 03/003377	01-09-2003	Intel Corporation		
		EP 0 468 758	01-29-1992	Semiconductor Energy Lab.		
		DE 198 11 068	06-24-1999	Siemens AG		
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Examiner Signature	[Signature]	Date Considered	8/2006
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Substitute for form 1449A/PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Application Number	10/816,259
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				Art Unit	2818
				Examiner Name	Le. Dung Anh
Sheet	2	of	2	Attorney Docket Number	42P19022

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No.†	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T*
		Kuo, Y., et al., "Tantalum Nitride Interface Layer Influence on Dielectric Properties of Hafnium Doped Tantalum Oxide High Dielectric Constant Thin Films", Japanese Journal of Applied Physics, Vol. 42, No. 7A, Part 2, 1 July 2003, pp. L769-L771. ✓	
		PCT Search Report and Written Opinion dated April 7, 2006 for International Application No. PCT/US2005/010921, filed 31 March 2005 (12 pages). ✓	

Examiner Signature		Date Considered	8/2006
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